Contents

List of Figures xi

List of Tables xv

Preface xvii

Acknowledgements xix

1 Introduction 1
- 1.1 Passive Elements 1
- 1.2 Figures of Merit of Varactors 3
  - 1.2.1 Quality Factor 3
  - 1.2.2 Tuning Range 4
  - 1.2.3 Self-resonant Frequency (f_R) 4
  - 1.2.4 Effective Silicon Area 5
  - 1.2.5 Absolute Capacity Value 5
- 1.3 Principal Types of Varactor Manufacture 5
  - 1.3.1 Discrete Varactors 5
  - 1.3.2 MEMS Varactors 6
  - 1.3.3 BST Varactors 7
  - 1.3.4 Integrated Varactors Using Standard Technologies 8

References 8

2 PN-junction Varactors 11
- 2.1 The Operating Principle of a PN-junction Varactor 11
  - 2.1.1 Electrical Phenomena in a PN-junction Varactor 13
- 2.2 Different Architectures of PN-junction Varactors 15
  - 2.2.1 Different Configurations of PN-junction Varactors 17
- 2.3 Influence of Bias Voltage on the Behaviour of a PN-junction Varactor 19
- 2.4 Influence of Geometric Parameters on the Behaviour of a PN-junction Varactor 20
  - 2.4.1 Influence in the Variation of the Number of Islands 20
  - 2.4.2 Influence of the Size of the Islands 21

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2.4.3 Influence of the Distance Between Islands 23
2.4.4 Variation of the Size of the N Well 24
2.5 Influence of the Working Frequency on the Results 25
2.5.1 Influence of the Frequency on the Quality of a Varactor 25
2.5.2 Influence of the Frequency on the Capacitance of a Varactor 26
2.6 Comparison Between the Different Types of PN-junction Varactors 28
2.6.1 Comparison According to the Effective Silicon Area 28
2.6.2 Comparison According to the Quality Factor 29
References 30

3 MOS Varactors 31
3.1 Operating Principles of an NMOS Varactor 31
3.1.1 Operating Ranges of the NMOS Varactor 32
3.1.2 Electrical Phenomena of an NMOS Varactor in Accumulation Mode 35
3.1.3 Electrical Phenomena of an NMOS Varactor in Depletion Mode 36
3.2 NMOS Varactors 38
3.2.1 Operating Ranges of the NMOS Varactor 38
3.3 Influence of the Operating Mode on an NMOS Varactor 41
3.4 Influence of Bias Voltage on the Behaviour of an NMOS Accumulation Varactor 44
3.5 Influence of Geometric Parameters on the Behaviour of an NMOS Varactor 45
3.5.1 Influence of the Variation of the Varactor Size 45
3.5.2 Influence of the Varactor Gate Length on its Performance 46
3.5.3 Influence of the Varactor Gate Width on its Performance 49
3.6 Influence of the Working Frequency on the Results 50
References 51

4 Measurement Techniques for Integrated Varactors 53
4.1 Test System 53
4.2 Equipment Required for the On-Wafer Testing of Integrated Varactors 54
4.2.1 Test Probes 54
4.2.2 Connectivity 54
4.3 Calibrating the Test System 55
4.4 Test Structures 56
4.4.1 Choosing the Test Structure Configuration 56

4.4.2 Design of the Test Structures 57
4.4.3 Effects Introduced by the Test Structures 59
4.5 Test Structure DE-embedding Techniques 61
4.5.1 Single–Short Structure 62
4.5.2 Single–Open Structure 63
4.5.3 Thru Structure 64
4.6 Characterization of Integrated Varactors 66
4.7 Test System Verification 67
4.7.1 Error Introduced by Positioning the Test Probes on the Pads 67
4.7.2 Error Introduced by the Calibration Reference Tolerances 68
4.7.3 Error Introduced by the Test Probes Heating up 69
4.7.4 Error Introduced by the Degradation of the Components 70
4.7.5 Analysis of the Results 72
References 72

5 Modeling Varactors 73
5.1 Introduction to the Modeling of Varactors 73
5.2 Modeling PN-junction Varactors 74
5.2.1 Value of Parameter L_1 76
5.2.2 Value of Parameter C_1 76
5.2.3 Value of Parameter R_1 77
5.2.4 Value of Parameter L_2 77
5.2.5 Value of Parameter C_2 77
5.2.6 Value of Parameter R_2 78
5.3 Modeling NMOS Varactors 78
5.3.1 Value of Parameter L_G 80
5.3.2 Value of Parameter C_{ox} 80
5.3.3 Value of Parameter C_{Si} 81
5.3.4 Value of Parameter C_{GD} 81
5.3.5 Value of Parameter R_1 82
5.3.6 Value of Parameter R_{N2} 82
5.3.7 Value of Parameter C_{NS} 82
5.3.8 Value of Parameter L_D/S 83

6 Design Rules for Integrated Varactors 85
6.1 Design Rules for PN-junction Integrated Varactors 85
6.2 Design Rules for NMOS Integrated Varactors 86
6.3 Comparison between Accumulation NMOS Varactors and PN-junction Varactors 86
References 88

7 Design of a Demonstrator: Integrated VCO **89**
7.1 Circuits Including Varactors 89
7.1.1 Influence of the Figures of Merit of the Varactor 90
7.1.2 Choosing the Demonstrator 96
7.2 General Considerations 96
7.2.1 Introduction 96
7.2.2 VCO Specifications 97
7.2.3 Active Circuit 100
7.2.4 Analysis of the CMOS Oscillator 103
7.3 Voltage-controlled Oscillator 106
7.3.1 Design of the Tank Circuit 106
7.3.2 Design of the Oscillator 113
7.3.3 VCO Measurements 115
7.3.4 PLL Measurements 119
References 122

Appendix 1: Geometric Characteristics of Varactors **123**
A1.1 Chip with the Varactors used in this Book 123
A1.2 Geometrical Characteristics of the PN-juntion Varactors 123
A1.2.1 Interdigit Varactors 123
A1.2.2 Island Varactors 123
A1.2.3 Matrix Varactors 125
A1.3 Geometrical Characteristics of MOS Varactors 126

Appendix 2: Validation of the Predictions Provided by Equations of Chapter 5 **129**
A2.1 PN-junction Varactor 129
A2.1.1 Inductance L_1 130
A2.1.2 Capacitance C_1 130
A2.1.3 Resistance R_1 132
A2.1.4 Inductance L_2 133
A2.1.5 Capacitance C_2 134
A2.1.6 Resistance R_2 134
A2.2 NMOS Varactors 135
A2.2.1 Inductance L_G 135
A2.2.2 Capacitance C_{ox} 136
A2.2.3 Capacitance C_{Si} 137
A2.2.4 Capacitance C_{GD} 139
A2.2.5 Resistance R_1 140
A2.2.6 Resistance R_{N2} 141
A2.2.7 Capacitance C_{NS} 141
A2.2.8 Inductance $L_{D/S}$ 141

Appendix 3: Measurement of Oscillator's Performance **143**
A3.1 Design of the Layout 143
A3.2 Measurement Set-up 148
A3.3 Oscillator and PLL Measurement 150
A3.3.1 Analysis and Calculation of the Loop Filter 150
A3.3.2 Printed Circuit Board Design 150
A3.3.3 Measurement Set-up 152

Glossary **155**

Index **157**